CBCX68 SERIES NPN CBCX69 SERIES PNP

SURFACE MOUNT COMPLEMENTARY SILICON SMALL SIGNAL TRANSISTORS



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CBCX68 and CBCX69 series types are complementary silicon transistors manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for applications requiring high current capability.

MARKING: FULL PART NUMBER



MAXIMUM RA	ATINGS: (T _A =25°C)	SYMBOL				UNITS		
Collector-Emit	ter Voltage	V _{CES}		25		V		
Collector-Emit	ter Voltage	V_{CEO}	20			V		
Emitter-Base \	/oltage	V_{EBO}	5.0			V		
Continous Col	lector Current	$I_{\mathbb{C}}$	1.0			Α		
Peak Collector	Current	I _{CM}		2.0		Α		
Continuous Ba	ase Current	Ι _Β	100			mA		
Peak Base Current		I _{BM}	200			mA		
Power Dissipation		P_{D}		1.2		W		
Operating and Storage Junction Temperature		T _J , T _{stg}	-6	55 to +150		°C		
Thermal Resistance		$\Theta_{\sf JA}$		104		°C/W		
ELECTRICAL CHARACTERISTICS: (T _A =25°C unless otherwise noted)								
SYMBOL	TEST CONDITIONS		ΛIN	TYP	MAX	UNITS		
I _{CBO}	V _{CB} =25V				100	nA		
I _{CBO}	V _{CB} =25V, T _A =150°C				10	μΑ		
I _{EBO}	V _{EB} =5.0V				10	μΑ		
BV_{CBO}	I _C =10μA		25			V		

STINIBUL	LEST CONDITIONS	IVIIIVI	117	IVIAA	UNITS
ICBO	V _{CB} =25V			100	nA
ICBO	V _{CB} =25V, T _A =150°C			10	μΑ
I _{EBO}	V _{EB} =5.0V			10	μΑ
BV _{CBO}	I _C =10μA	25			V
BVCEO	I _C =10mA	20			V
BV_{EBO}	I _E =10μA	5.0			V
V _{CE} (SAT)	I _C =1.0A, I _B =100mA			0.5	V
V _{BE(ON)}	V_{CE} =10V, I_{C} =5.0mA		0.6		V
V _{BE(ON)}	V _{CE} =1.0V, I _C =1.0A			1.0	V
hFE	V _{CE} =10V, I _C =5.0mA	50			
hFE	V_{CE} =1.0V, I_{C} =500mA (CBCX68, CBCX69)	85		375	
h_{FE}	V _{CE} =1.0V, I _C =500mA (CBCX68-16, CBCX69-16)	100		250	
hFE	V _{CE} =1.0V, I _C =500mA (CBCX68-25, CBCX69-25)	160		400	
hFE	V_{CE} =1.0V, I_{C} =1.0A	60			
f _T	V_{CE} =5.0V, I_{C} =10mA, f=20MHz	65			MHz

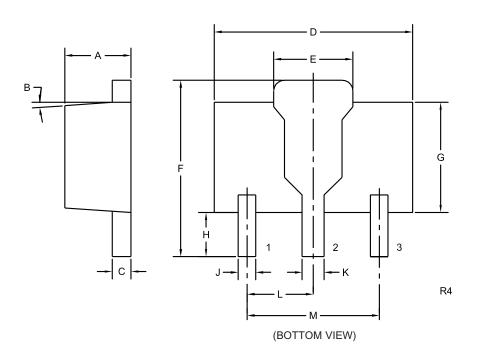
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SOT-89 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) EMITTER
- 2) COLLECTOR 3) BASE

MARKING: FULL PART NUMBER

DIMENSIONS								
	INC	HES	MILLIMETERS					
SYMBOL	MIN	MAX	MIN	MAX				
Α	0.055	0.067	1.40	1.70				
В	4	0	4°					
С	0.014	0.018	0.35	0.46				
D	0.173	0.185	4.40	4.70				
Е	0.064	0.074	1.62	1.87				
F	0.146	0.177	3.70	4.50				
G	0.090	0.106	2.29	2.70				
Н	0.028	0.051	0.70	1.30				
J	0.014	0.019	0.36	0.48				
K	0.017	0.023	0.44	0.58				
L	0.0)59	1.50					
М	0.1	18	3.00					
COT 90 (DEV) D4)								

SOT-89 (REV: R4)

R11 (23-February 2012)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- · Application notes
- · Application and design sample kits
- Custom product and package development

CONTACT US

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